July 2009



FGI40N60SF 600V, 40A Field Stop IGBT

Features

- High current capability
- Low saturation voltage: V_{CE(sat)} =2.3V @ I_C = 40A
- High input impedance
- Fast switching
- RoHS compliant

Applications

• Induction Heating, UPS, SMPS, PFC



General Description

Using Novel Field Stop IGBT Technology, Fairchild's new sesries of Field Stop IGBTs offer the optimum performance for Induction Heating, UPS, SMPS and PFC applications where low conduction and switching losses are essential.



Absolute Maximum Ratings

Symbol	Description		Ratings	Units	
V _{CES}	Collector to Emitter Voltage		600	V	
V _{GES}	Gate to Emitter Voltage		± 20	V	
Ι _C	Collector Current	@ T _C = 25 ^o C	80	A	
	Collector Current	@ T _C = 100°C	40	A	
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25 ^o C	120	A	
P _D	Maximum Power Dissipation	@ T _C = 25°C	290	W	
	Maximum Power Dissipation	@ T _C = 100 ^o C	116	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

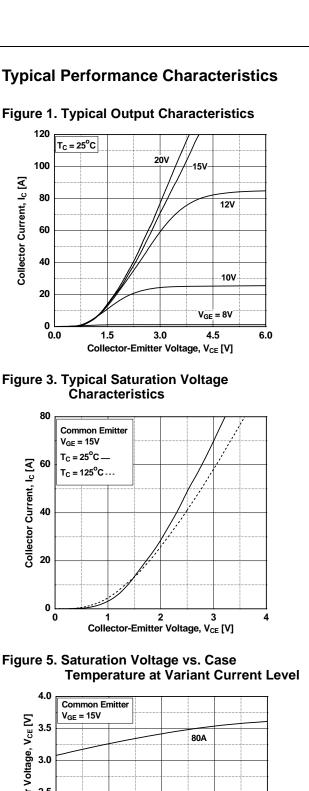
Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

Device N	evice Marking Device F		Packaging ackageTO262Tube		Qty per Tube		Max Qty per Box -	
FGI40N60SF		FGI40N60SFTU						
Electric	al Char	acteristics of the I	GBT T _C = 25	°C unless otherwise noted				
Symbol		Parameter	Test	Conditions	Min.	Тур.	Max.	Units
Off Charac	teristics							
BV _{CES}	Collector	to Emitter Breakdown Voltage	$V_{GE} = 0V, I_C$	= 250µA	600	-	-	V
ΔΒV _{CES} ΔΤ _J	Temperate Voltage	ure Coefficient of Breakdown	$V_{GE} = 0V, I_C = 250\mu A$		-	0.6	-	V/ºC
ICES	Collector	Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$		-	-	250	μA
I _{GES}	G-E Leak	age Current	$V_{GE} = V_{GES},$	$V_{CE} = 0V$	-	-	±400	nA
On Charac	teristics							
V _{GE(th)}	1	shold Voltage	I _C = 250μA, ¹	V _{CE} = V _{GE}	4.0	5.0	6.5	V
			I _C = 40A, V _{GE} = 15V		-	2.3	2.9	V
V _{CE(sat)}	Collector	to Emitter Saturation Voltage			-	2.5	-	V
Dynamic C	haracteris	tics	+		-1	ł		4
C _{ies}	Input Cap				-	2110	-	pF
C _{oes}	Output Ca	apacitance	$V_{CE} = 30V$, $V_{GE} = 0V$, f = 1MHz		-	200	-	pF
C _{res}	Reverse 7	Fransfer Capacitance			-	60	-	pF
Switching	Characteri	stics						
t _{d(on)}	1	Delay Time			-	25	-	ns
t _r	Rise Time	•			-	42	-	ns
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 400V,	lc = 40A.	-	115	-	ns
t _f	Fall Time		R _G = 10Ω, V	$R_G = 10\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 25^{\circ}C$		27	54	ns
E _{on}	Turn-On S	Switching Loss	Inductive Loa			1.13	-	mJ
E _{off}	Turn-Off S	Switching Loss	1			0.31	-	mJ
E _{ts}	Total Swit	ching Loss	+		-	1.44	-	mJ
t _{d(on)}	Turn-On [Delay Time			-	24	-	ns
t _r	Rise Time)			-	43	-	ns
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 400V,	I _C = 40A,	-	120	-	ns
t _f	Fall Time		R _G = 10Ω, V	R _G = 10Ω, V _{GE} = 15V,		30	-	ns
	Turn-On S	Switching Loss	Inductive Load, T _C = 125 ^o C	-	1.14	-	mJ	
			1		-	0.48	-	mJ
E _{on}	Turn-Off S	Switching Loss				0.10		
E _{on} E _{off}		Switching Loss ching Loss	_		-	1.62	-	mJ
E _{on} E _{off} E _{ts} Q _g		ching Loss	V _{CE} = 400V,		-		-	mJ nC



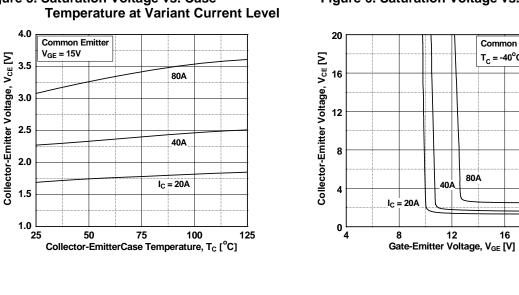


Figure 2. Typical Output Characteristics

20V

15V

12V

120

100

80

60

T_C = 125^oC

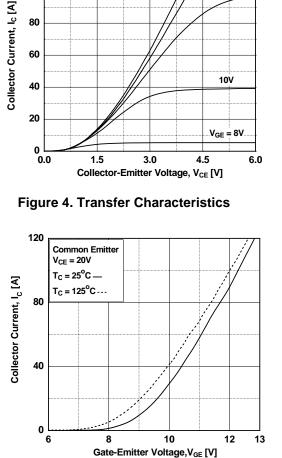


Figure 6. Saturation Voltage vs. V_{GE}

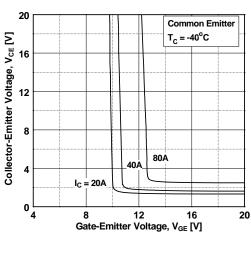


Figure 7. Saturation Voltage vs. V_{GE} 20 Common Emitter Collector-Emitter Voltage, V_{CE} [V] $T_{C} = 25^{\circ}C$ 16 12 8 80A 40A 4 = 20A 0 ∟ 4 8 12 16 20 Gate-Emitter Voltage, V_{GE} [V] **Figure 9. Capacitance Characteristics** 5000

Typical Performance Characteristics

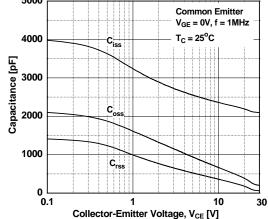


Figure 11. SOA Characteristics

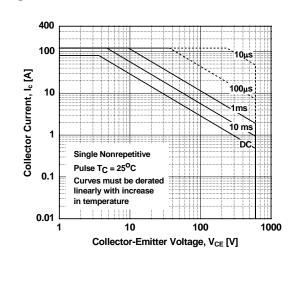


Figure 8. Saturation Voltage vs. V_{GE}

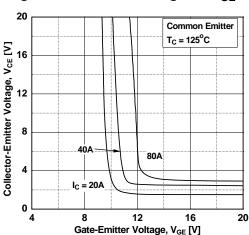


Figure 10. Gate charge Characteristics

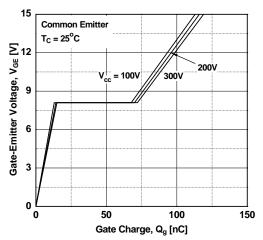
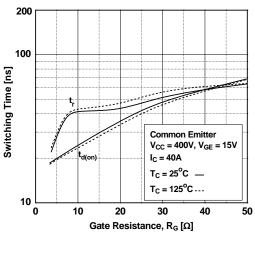
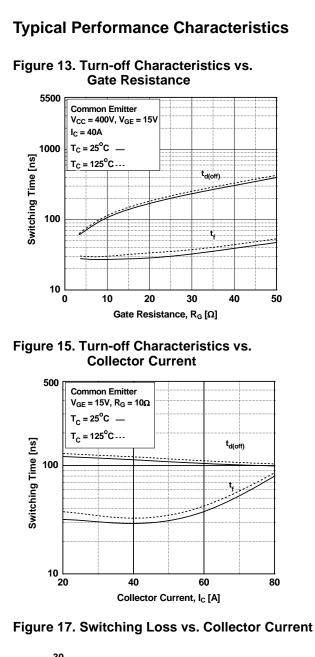
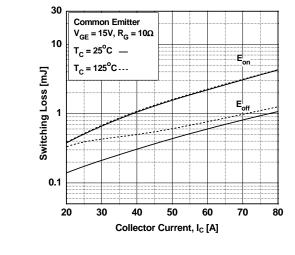
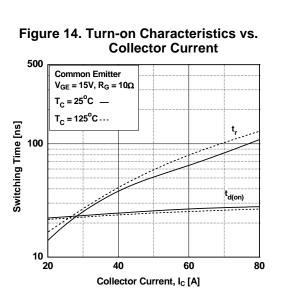


Figure 12. Turn-on Characteristics vs. Gate Resistance











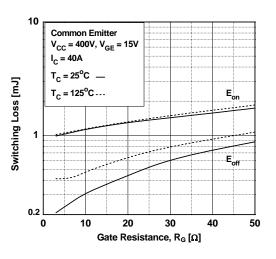
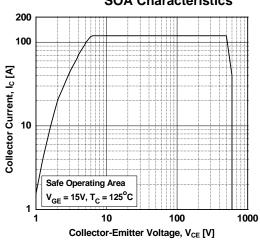
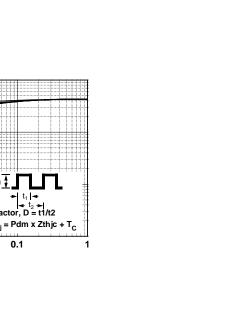


Figure 18. Turn off Switching SOA Characteristics

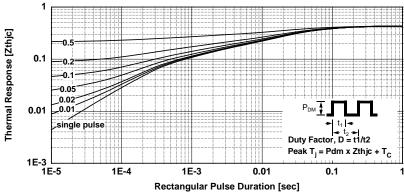


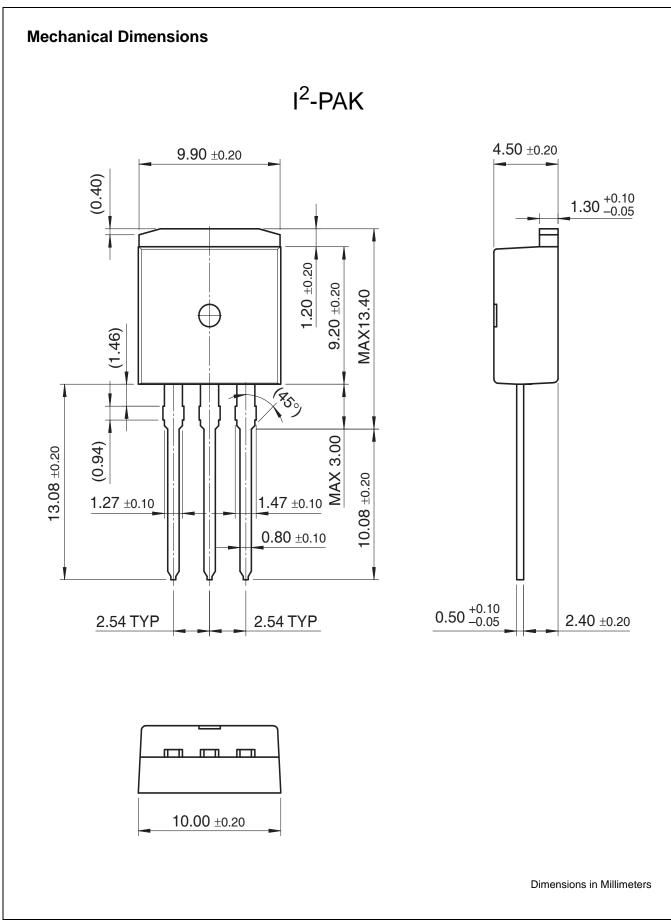


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Typical Performance Characteristics

Figure 19. Transient Thermal Impedance of IGBT





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